MOS FET Relays

G3VM-401BY/EY

Analog-switching MOS FET Relay with Dielectric Strength of 5 kVAC between I/O Using Optical Isolation.

- Switches minute analog signals.
- \bullet Leakage current of 1 μA max. when output relay is open.

■ Application Examples

- Electronic automatic exchange systems
- Measurement devices
- FA systems



87

10.0 max

Weight: 0.38 g

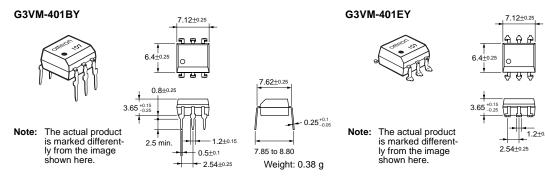
Note: The actual product is marked differently from the image shown here.

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	400 VAC	G3VM-401BY	50	
	Surface-mount-		G3VM-401EY		
	ing terminals		G3VM-401EY (TR)		1,500

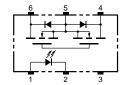
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

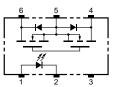


■ Terminal Arrangement/Internal Connections (Top View)



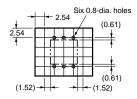


G3VM-401EY

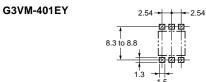


■ PCB Dimensions (Bottom View)

G3VM-401BY



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

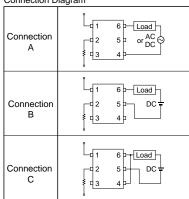


■ Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current		I _F	50	mA		
	Repetitive peak LED forward current		I _{FP}	1	Α	100 μs pulses, 100 pps	
	LED forward current reduction rate		Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C	
	LED reverse voltage		V_R	5	V		
	Connection temperature		Tj	125	°C		
Output	Output dielectric strength		V _{OFF}	400	V		
	Continuous load current	Connection A	I _O	120	mA		
		Connection B		120			
		Connection C		240			
	ON current reduction rate	Connection A	Δ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C	
		Connection B		-1.2			
		Connection C		-2.4			
	Connection temperature		Tj	125	°C		
Dielectric strength between input and output (See note 1.)		V _{I-O}	5,000	Vrms	AC for 1 min		
Operating temperature			Ta	-40 to +85	°C	With no icing or condensation	
Storage temperature			T _{stg}	-55 to +125	°C	With no icing or condensation	
Soldering temperature (10 s)				260	°C	10 s	

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

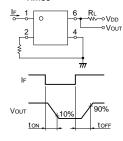
Connection Diagram



■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage		V_{F}	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	Reverse current				10	μА	V _R = 5 V	
	Capacity between terminals		C _T		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current		I _{FT}			3	mA	I _O = 120 mA	
Output	Maximum resistance with output ON	Connection A	R _{ON}		17	35	Ω	I _F = 5 mA, I _O = 120 mA	
		Connection B			11	20	Ω	I _F = 5 mA, I _O = 120 mA	
		Connection C			6	10	Ω	I _F = 5 mA, I _O = 240 mA	
	Current leakage when the relay is open		I _{LEAK}			1.0	μА	V _{OFF} = 400 V	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V		
Insulation resistance		R _{I-O}	1,000			ΜΩ	V_{I-O} = 500 VDC, RoH \leq 60%		
Turn-ON time			tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega$ $V_{DD} = 20 \text{ V (See note 2)}$	
Turn-OFF time		tOFF		0.1	1.0	ms			

Note: 2. Turn-ON and Turn-OFF



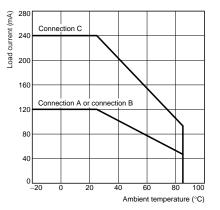
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}			320	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	I _O			120	mA
Operating temperature	Ta	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-401BY(EY)



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.